





2N5397-8

2N5397, 2N5398 N-Channel JFET

Support

Features

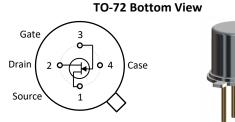
- InterFET N0026L Geometry
- Low Noise: 3 nV/vHz Typical
- Low Ciss: 5.0pF Typical
- Low Leakage: 10pA Typical
- RoHS Compliant
- SMT, TH, and Bare Die Package options.

Applications

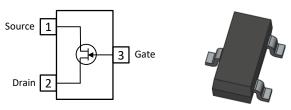
- Low Noise
- High Power Gain
- High Transconductance
- Mixers
- Oscillators
- VHF Amplifiers

Description

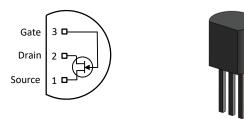
The -25V InterFET 2N5397 and 2N5398 are targeted for low noise amplifier stages as well as mixer and oscillator designs. Gate leakages are typically less than 10pA at room temperatures. The TO-72 package is hermetically sealed and suitable for military applications.







TO-92 Bottom View



Product Summary

| | Parameters | 2N5397 Min | 2N5398 Min | Unit |
|----------------------|------------------------------------|------------|------------|------|
| BV _{GSS} | Gate to Source Breakdown Voltage | -25 | -25 | V |
| IDSS | Drain to Source Saturation Current | 10 | 5 | mA |
| V _{GS(off)} | Gate to Source Cutoff Voltage | -1 | -1 | V |
| G _{FS} | Forward Transconductance | 5.5 | 5 | mS |

Ordering Information Custom Part and Binning Options Available

| Part Number | Description | Case | Packaging |
|----------------------|--|-------|----------------------|
| 2N5397; 2N5398 | Through-Hole | TO-72 | Bulk |
| PN5397; PN5398 | Through-Hole | TO-92 | Bulk |
| SMP5397; SMP5398 | Surface Mount | SOT23 | Bulk |
| | 7" Tape and Reel: Max 3,000 Pieces | | Minimum 1,000 Pieces |
| SMP5397TR; SMP5398TR | 13" Tape and Reel: Max 9,000 Pieces | SOT23 | Tape and Reel |
| 2N5397COT; 2N5398COT | Chip Orientated Tray (COT Waffle Pack) | COT | 400/Waffle Pack |
| 2N5397CFT; 2N5398CFT | Chip Face-up Tray (CFT Waffle Pack) | CFT | 400/Waffle Pack |



Disclaimer: It is the Buyers responsibility for designing, validating and testing the end application under all field use cases and extreme use conditions. Guaranteeing the application meets required standards, regulatory compliance, and all safety and security requirements is the responsibility of the Buyer. These resources are subject to change without notice.







Electrical Characteristics

Maximum Ratings (@ T_A = 25°C, Unless otherwise specified)

| | Parameters | Value | Unit |
|------------------|--|------------|-------|
| VRGS | Reverse Gate Source and Gate Drain Voltage | -25 | V |
| I_{FG} | Continuous Forward Gate Current | 10 | mA |
| PD | Continuous Device Power Dissipation | 300 | mW |
| Р | Power Derating | 1.7 | mW/°C |
| Τı | Operating Junction Temperature | -55 to 125 | °C |
| T _{STG} | Storage Temperature | -65 to 150 | °C |

Static Characteristics (@ TA = 25°C, Unless otherwise specified)

| | | | 2N5397 | | 2N5398 | | |
|--------------------|---------------------------------------|---|--------|--------------|--------|--------------|----------|
| | Parameters | Conditions | Min | Max | Min | Max | Unit |
| V(BR)GSS | Gate to Source Breakdown Voltage | $V_{DS} = 0V, I_{G} = -1\mu A$ | -25 | | -25 | | v |
| IGSS | Gate to Source Reverse Current | V _{GS} = -15V, V _{DS} = 0V, T _A = 25°C V _{GS} = -15V, V _{DS} = 0V, T _A = 150°C | | -0.1 -0.1 | | -0.1 -0.1 | nA μA |
| V _{GS(F)} | Gate to Source Forward Voltage | $V_{DS} = 0V, I_G = 1mA$ | | 1 | | 1 | v |
| Vgs(off) | Gate to Source Cutoff Voltage | V _{DS} = 10V, I _D = 1nA | -1 | 6 | -1 | -6 | V |
| I _{DSS} | Drain to Source Saturation Current | $V_{GS} = 0V, V_{DS} = 10V$ (Pulsed) | 10 | 30 | 5 | 40 | mA |

Dynamic Characteristics (@ TA = 25°C, Unless otherwise specified)

| | | | 2N5397 | | 2N5398 | | |
|------------------|---------------------------------|--|--------|-----|--------|-----|------|
| | Parameters | Conditions | Min | Max | Min | Max | Unit |
| GFS | Forward Transconductance | V _{DS} = 10V, I _D = 10mA, f = 450MHz | 5.5 | 9 | 5 | 10 | mS |
| Gos | Output Conductance | V _{DS} = 10V, I _D = 10mA, f = 450MHz | | 0.4 | | 0.5 | mS |
| Gıs | Input Conductance | V _{DS} = 10V, I _D = 10mA, f = 450MHz | | 2 | | 3 | mS |
| Ciss | Input Capacitance | V _{DS} = 15V, V _{GS} = 0V, f = 1MHz | | 5 | | 5.5 | pF |
| C _{rss} | Reverse Transfer Capacitance | V_{DS} = 15V, V_{GS} = 0V, f = 1MHz | | 1.2 | | 1.3 | pF |

RF Parameters guaranteed, but not 100% tested.



Technical

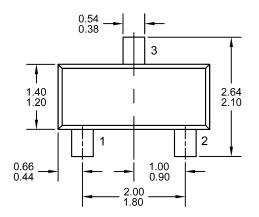
Support

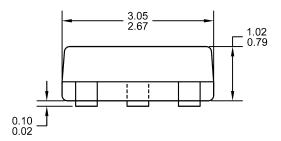
Order

Now

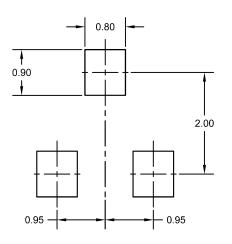
SOT23 (TO-236AB) Mechanical and Layout Data

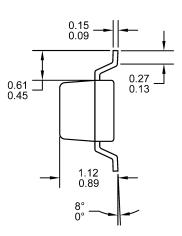
Package Outline Data





Suggested Pad Layout





- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.12 grams
- 3. Molded plastic case UL 94V-0 rated
- For Tape and Reel specifications refer to InterFET CTC-021 Tape and Reel Specification, Document number: IF39002
- 5. Bulk product is shipped in standard ESD shipping material
- 6. Refer to JEDEC standards for additional information.

- 1. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided for reference only. A more robust pattern may be desired for wave soldering.





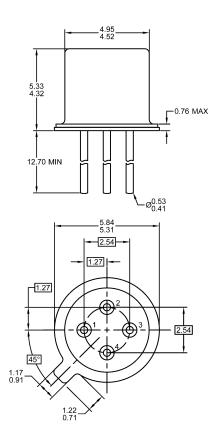
Order

Now

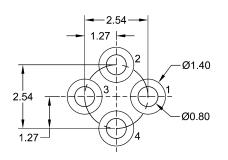
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TO-72 Mechanical and Layout Data

Package Outline Data



Suggested Through-Hole Layout



- 1. All linear dimensions are in millimeters.
- 2. Four leaded device. Not all leads are shown in drawing views.
- 3. Package weight approximately 0.31 grams
- 4. Bulk product is shipped in standard ESD shipping material
- 5. Refer to JEDEC standards for additional information.

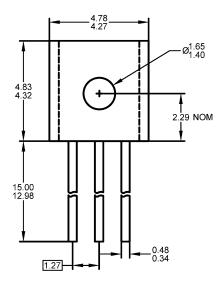
- 1. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided as a straight lead reference only. A more robust pattern may be desired for wave soldering and/or bent lead configurations.

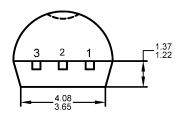




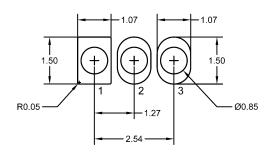
TO-92 Mechanical and Layout Data

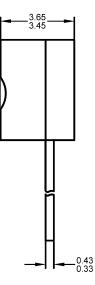
Package Outline Data





Suggested Through-Hole Layout





- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.19 grams
- 3. Molded plastic case UL 94V-0 rated
- 4. Bulk product is shipped in standard ESD shipping material
- 5. Refer to JEDEC standards for additional information.

- 1. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided as a straight lead reference only. A more robust pattern may be desired for wave soldering and/or bent lead configurations.

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